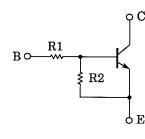
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

RN1101F,RN1102F,RN1103F RN1104F,RN1105F,RN1106F

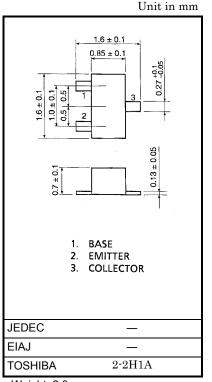
Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2101F~RN2106F

Equivalent Circuit And Bias Resister Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN1101F	4.7	4.7
RN1102F	10	10
RN1103F	22	22
RN1104F	47	47
RN1105F	2.2	47
RN1106F	4.7	47



Maximum Ratings (Ta = 25°C)

Weight: 2.3 mg

Characteris	Symbol	Rating	Unit		
Collector-base voltage	RN1101F~1106F	V _{CBO}	50	V	
Collector-emitter voltage		V _{CEO}	50	V	
Emitter-base voltage	RN1101F~1104F	V _{FBO}	10	V	
Emilier-base vollage	RN1105F, 1106F	▲EBO	5		
Collector current		Ι _C	100	mA	
Collector power dissipation	RN1101F~1106F	PC	100	mW	
Junction temperature	KNTIOTE~TIOOF	Тј	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

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TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general
can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the
buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and
to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or
damage to property.

In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc...

• The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.

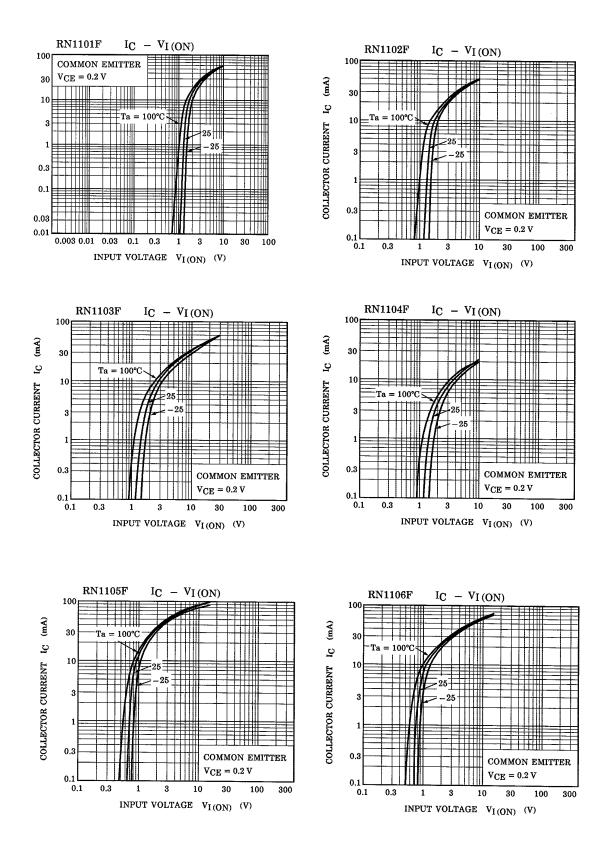
Electrical Characteristics (Ta = 25°C)

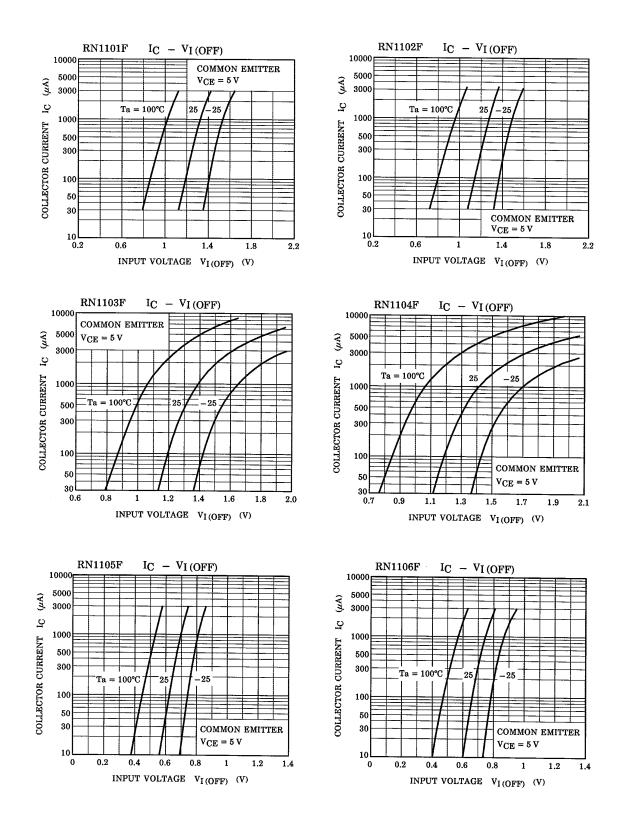
Characteristic		Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN1101F	I _{CBO}		$V_{CB} = 50V, I_E = 0$	—	-	100	nA
	~1106F	I _{CEO}		V _{CE} = 50V, I _B = 0	-	_	500	
	RN1101F	– – I _{ЕВО} –	_	V _{EB} = 10V, I _C = 0	0.82	_	1.52	mA
	RN1102F				0.38	_	0.71	
Facilities and aff annual	RN1103F				0.17	-	0.33	
Emitter cut-off current	RN1104F				0.082	_	0.15	
	RN1105F			V _{EB} = 5V, I _C = 0	0.078	_	0.145	
	RN1106F			VEB - 5V, IC - 0	0.074	_	0.138	
	RN1101F				30	_	_	·
	RN1102F			V _{CE} = 5V, I _C = 10mA	50	_	_	
	RN1103F	h _{FE}			70	_	_	
DC current gain	RN1104F		-		80	_	_	
	RN1105F				80	_	_	
	RN1106F				80	—	_	
Collector-emitter saturation voltage	RN1101F ~1106F	V _{CE (sat)}	_	I _C = 5mA, I _B = 0.25mA	_	0.1	0.3	V
	RN1101F	VI (ON)		V _{CE} = 0.2V, I _C = 5mA	1.1	—	2.0	V
	RN1102F				1.2	_	2.4	
	RN1103F		_		1.3	_	3.0	
Input voltage (ON)	RN1104F				1.5	_	5.0	
	RN1105F				0.6	_	1.1	
	RN1106F				0.7	_	1.3	
	RN1101F ~1104F			V _{CE} = 5V, I _C = 0.1mA	1.0	_	1.5	· v
Input voltage (OFF)	RN1105F, 1106F	VI (OFF)	(OFF) —		0.5	_	0.8	
Transition frequency	RN1101F ~1106F	f _T	-	V _{CE} = 10V, I _C = 5mA	_	250	_	MH_{Z}
Collector Output capacitance	RN1101F ~1106F	C _{ob}	—	$V_{CB} = 10V, I_E = 0, f = 1MH_z$	-	3	6	pF
	RN1101F			3.29	4.7	6.11		
	RN1102F	F R1 F	_	_	7	10	13	kΩ
Innut register	RN1103F				15.4	22	28.6	
Input resistor	RN1104F				32.9	47	61.1	
	RN1105F				1.54	2.2	2.86	
	RN1106F				3.29	4.7	6.11	
	RN1101F ~1104F			_	0.9	1.0	1.1	
Resistor ratio	RN1105F		-		0.0421	0.0468	0.0515	
	RN1106F				0.09	0.1	0.11	

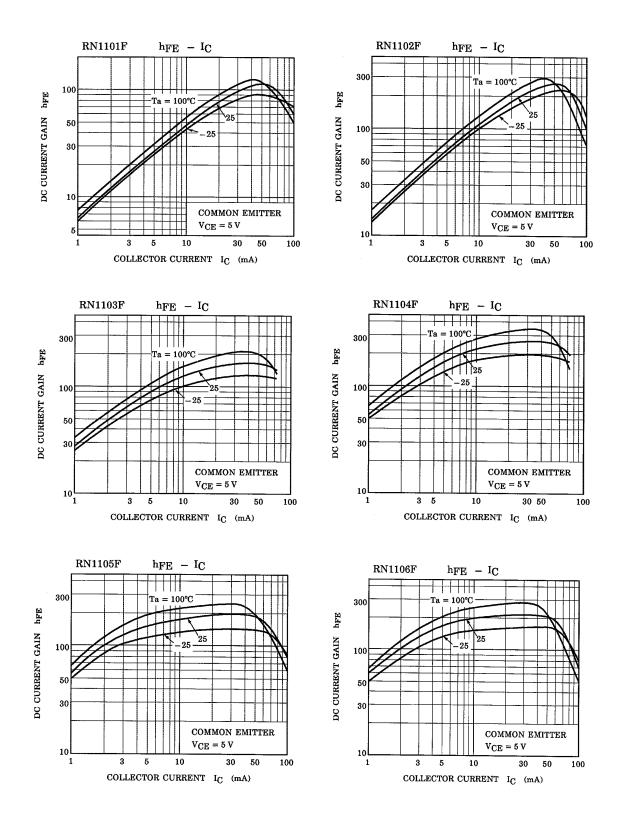
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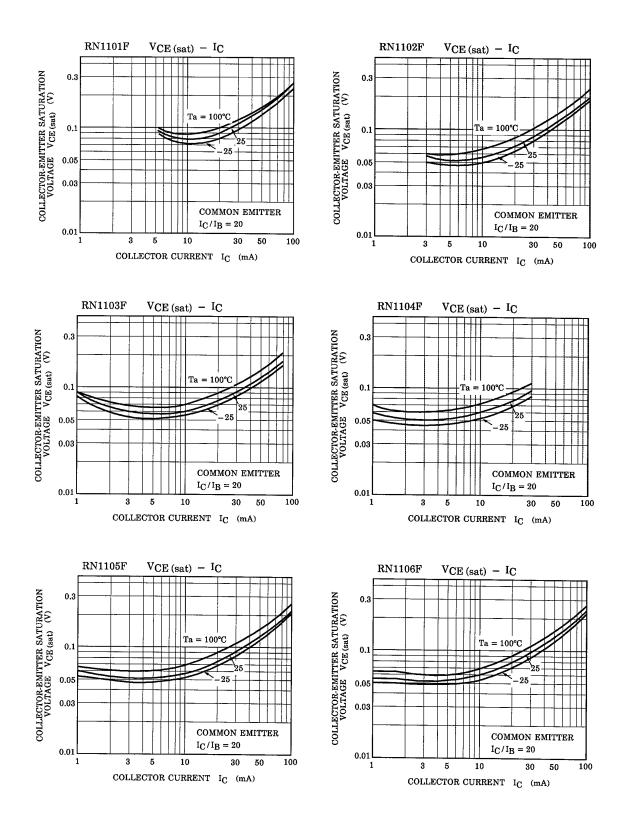
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The information contained herein is subject to change without notice.









TOSHIBA

Type Name	Marking
RN1101F	Type Name X A
RN1102F	Type Name X B
RN1103F	Type Name X C
RN1104F	Type Name X D
RN1105F	
RN1106F	Type Name X F